TS4148 RYG

Taiwan Semiconductor



150mA, 75V Switching Diode

FEATURES

- Low power loss, high efficiency
- Ideal for automated placement
- High surge current capability
- Moisture sensitivity level: level 1, per J-STD-020
- Compliance to RoHS directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21

APPLICATIONS

- Switching mode power supply (SMPS)
- Adapters
- Lighting application
- On-board DC/DC converter

MECHANICAL DATA

- Case: 0805(Ceramics)
- Molding compound meets UL flammability classification rating 94HB
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 1A whisker test
- Polarity: Indicated by cathode band
- Weight: 0.006g (approximately)

KEY PARAMETERS				
PARAMETER	VALUE	UNIT		
I _{F(AV)}	150	mA		
V _{RRM}	75	V		
I _{FSM}	2	А		
V _F at I _F =100mA	1.00	V		
TJMax.	175	°C		
Package	0805 (Ceramics)			
Configuration	Single die			







ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)					
PARAMETER		SYMBOL	VALUE	UNIT	
Repetitive peak reverse voltage		V _{RRM}	75	V	
Forward current		I _{F(AV)}	150	mA	
Non-repetitive peak forward surge current	tp = 1s square wave		0.5	A	
	tp = 8.3ms single half sine wave	I _{FSM}	2.0		
Junction temperature range		TJ	-55 to +175	°C	
Storage temperature range		T _{STG}	-55 to +175	°C	

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	TYP.	UNIT	
Junction-to-ambient thermal resistance	R _{eja}	375	°C/W	



TS4148 RYG Taiwan Semiconductor

ELECTRICAL SPECIFICATIONS (T _A = 25°C unless otherwise noted)					
PARAMETER	CONDITIONS	SYMBOL	TYP.	MAX.	UNIT
Forward voltage per diode (1)	I _F =100mA, T _J =25°C	V _F	-	1	V
Reverse current @ rated V _R per	V _R =20V T _J =25°C		-	25	nA
diode ⁽²⁾	V _R =75V T _J =25°C	I _R	-	5	μA
Reverse recovery time	I_F =10mA, I_R =10mA, R_L =100 Ω	t _{rr}	-	4	ns
Junction capacitance	1 MHz, V _R =0V	CJ	-	4	pF

Notes:

1. Pulse test with PW=0.3 ms

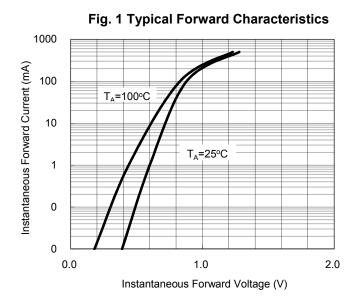
2. Pulse test with PW=30 ms

ORDERING INFORMATION			
ORDERING CODE	PACKAGE	PACKING	
TS4148 RYG	0005	5K / 7" Reel	
TS4148 RBG	0805	10K / 13" Reel	



CHARACTERISTICS CURVES

 $(T_A = 25^{\circ}C \text{ unless otherwise noted})$



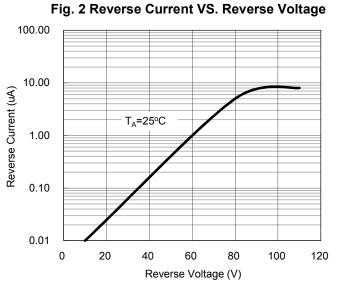


Fig. 3 Admissible Power Dissipation Curve

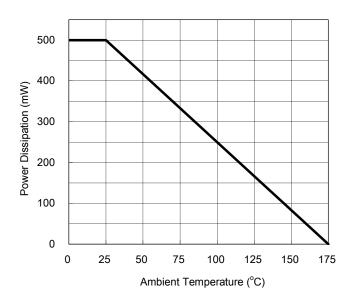
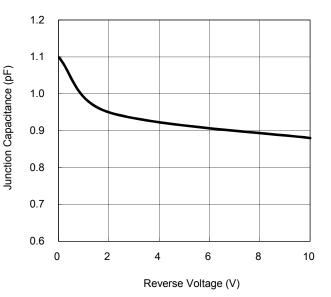


Fig. 4 Typical Junction Capacitance



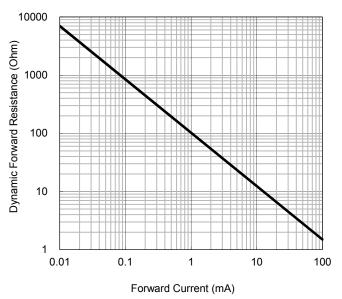


CHARACTERISTICS CURVES

(T_A = 25°C unless otherwise noted)

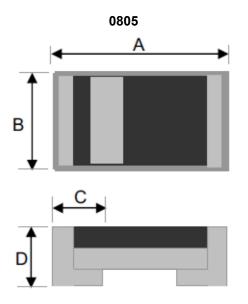


Forward Current





PACKAGE OUTLINE DIMENSION



DIM.	Unit (mm)	Unit (inch)		
DIN.	Min	Max	Min	Max	
А	1.80	2.20	0.071	0.087	
В	1.05	1.45	0.041	0.057	
С	0.25	0.65	0.010	0.026	
D	0.65	0.85	0.026	0.033	



Taiwan Semiconductor

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.